

HMC194MS8

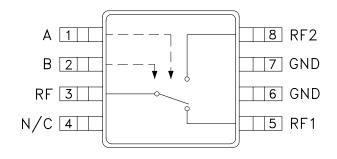
GaAs MMIC SPDT SWITCH DC - 3 GHz

Typical Applications

The HMC194MS8 is ideal for:

- Cellular/PCS Base Stations
- Portable Wireless
- MMDS & WirelessLAN

Functional Diagram



Features

Ultra Small Package: MSOP8

High Isolation: 50 dB

Positive Control: 0/+3V to 0/+7V

General Description

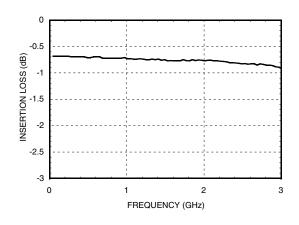
The HMC194MS8 is a low-cost SPDT switch in an 8-lead MSOP package for use in applications which require high isolation between two RF paths. The device can control signals from DC to 3 GHz and has been optimized to provide extremely high isolation with minimal insertion loss in medium and low power applications. On chip circuitry allows positive voltage control operation at very low DC currents with control inputs compatible with CMOS and most TTL logic families. RF1 and RF2 are reflective opens when "OFF".

Electrical Specifications, $T_A = +25^{\circ}$ C, Vctl = 0/+5 Vdc, 50 Ohm System

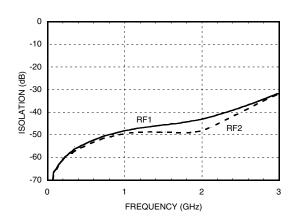
Parameter	Frequency	Min.	Тур.	Max.	Units
Insertion Loss	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz		0.7 0.7 0.8 0.9	0.9 0.9 1.1 1.4	dB dB dB dB
RF1 / RF2 Isolation	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz	45 / 47 39 / 43 31 24	49 / 51 42 / 46 35 28		dB dB dB dB
Return Loss	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz	18 14 13 13	21 17 17 17		dB dB dB dB
Input Power for 1 dB Compression 0/+5V Control	0.5 - 1.0 GHz 0.5 - 3.0 GHz	19 17	23 21		dBm dBm
Input Third Order Intercept 0/+5V Control (Two-tone Input Power = +7 dBm Each Tone)	0.5 - 1.0 GHz 0.5 - 3.0 GHz	39 37	43 41		dBm dBm
Switching Characteristics	DC - 3.0 GHz				
tRISE, tFALL (10/90% RF) tON , tOFF (50% CTL to 10/90% RF)			10 24		ns ns



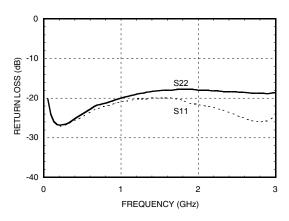
Insertion Loss



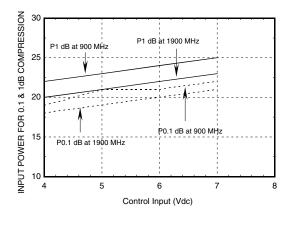
Isolation



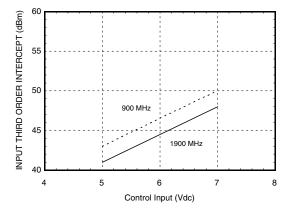
Return Loss



Input 0.1 and 1.0 dB Compression vs. Control Voltage



Input Third Order Intercept Point vs. Control Voltage





Compression vs. Control Voltage

	Carrier at 900 MHz		Carrier at 1900 MHz		
Bias Vdd	Input Power for 0.1 dB Compression	Input Power for 1.0 dB Compression	Input Power for 0.1 dB Compression	Input Power for 1.0 dB Compression	
(Vdc)	(dBm)	(dBm)	(dBm)	(dBm)	
+4	19	22	18	20	
+5	21	23	19	21	
+6	21	24	20	22	
+7	22	25	21	23	

Caution: Do not operate in 1dB compression at power levels above +25 dBm and do not "hot switch" power levels greater than +18 dBm (Control = 0/+5Vdc).

DC blocks are required at ports RFC, RF1 and RF2.

Distortion vs. Control Voltage

Control Input	Third Order Intercept (dBm) +7 dBm Each Tone		
(Vdc)	900 MHz	1900 MHz	
+5	43	41	
+7	50	48	

Truth Table

*Control Input Voltage Tolerances are ± 0.2 Vdc.

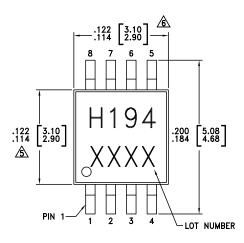
Contro	I Input*	Control Current Sign		Signal Pa	Path State	
A (Vdc)	B (Vdc)	la (uA)	lb (uA)	RF to RF1	RF to RF2	
0	+3	-23	+23	ON	OFF	
+3	0	+23	-23	OFF	ON	
0	+5	-95	+95	ON	OFF	
+5	0	+95	-95	OFF	ON	
0	+7	-190	+190	ON	OFF	
+7	0	+190	-190	OFF	ON	

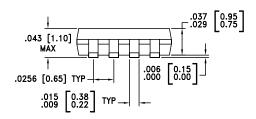


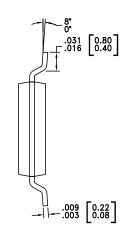
Absolute Maximum Ratings

Control Voltage Range (A & B)	-0.2 to +7.5 Vdc	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	

Outline Drawing





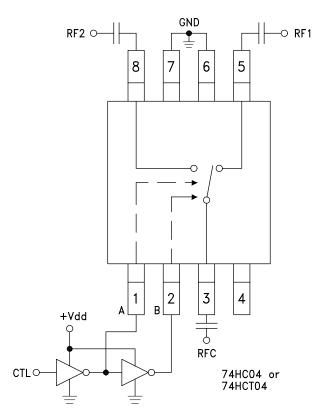


NOTES:

- PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
- 2. LEADFRAME MATERIAL: COPPER ALLOY
- 3. LEADFRAME PLATING: Sn/Pb SOLDER
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- 6 DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 7. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.



Typical Application Circuit



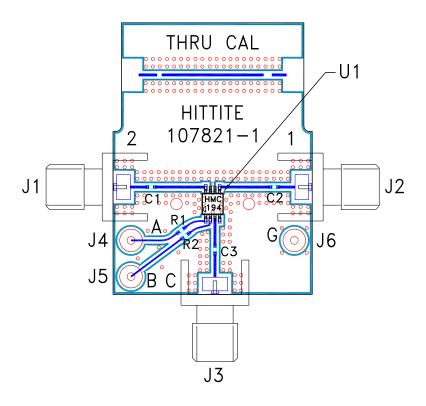
Notes:

- 1. Set logic gate and switch Vdd = +3V to +5V and use HCT series logic to provide a TTL driver interface.
- 2. Control inputs A/B can be driven directly with CMOS logic (HC) with Vdd of 3 to 7 Volts applied to the CMOS logic gates.
- 3. DC Blocking capacitors are required for each RF port as shown. Capacitor value determines lowest frequency of operation.
- 4. Highest RF signal power capability is achieved with Control set to 0/+7V.

See "Design Techniques Enhance Isolation in Switch Assemblies" for HMC194MS8 Applications, "Application Notes" Section.



Evaluation Circuit Board



List of Material

Item	Description	
J1 - J3	PC Mount SMA RF Connector	
J4 - J6	DC Pin	
C1 - C3	100 pF capacitor, 0402 Pkg.	
R1, R2	100 Ω resistor, 0402 Pkg.	
U1 HMC194MS8 SPDT Switch		
PCB*	107821 Evaluation PCB	
* Circuit Board Material: Rogers 4350		

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.